

MCH3218 — NPN Epitaxial Planar Silicon Transistor **DC / DC Converter Applications**

Applications

· Relay drivers, lamp drivers, motor drivers, flash.

Features

- · Adoption of MBIT processes.
- · Large current capacitance.
- · Low collector-to-emitter saturation voltage.
- · High-speed switching.
- Narrow hFE range.
- Ultrasmall package facilitates miniaturization in end products (mounting height : 0.85mm).
- · High allowable power dissipation.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		40	V
Collector-to-Emitter Voltage	VCEO		30	V
Emitter-to-Base Voltage	VEBO		6	V
Collector Current	IC		1.5	А
Collector Current (Pulse)	ICP		3	А
Base Current	ΙB		300	mA
Collector Dissipation	PC	Mounted on a ceramic board (600mm ² X0.8m)	0.7	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Sumbol	Conditions	Ratings			1.114	
	Symbol		min	typ	max	Unit	
Collector Cutoff Current	ICBO	V _{CB} =30V, I _E =0			0.1	μΑ	
Emitter Cutoff Current	IEBO	VEB=4V, IC=0			0.1	μΑ	
DC Current Gain	hFE	V _{CE} =2V, I _C =100mA	250		400		
Gain-Bandwidth Product	fT	V _{CE} =10V, I _C =300mA		500		MHz	
Output Capacitance	Cob	VCB=10V, f=1MHz		7		pF	
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Marking : CN

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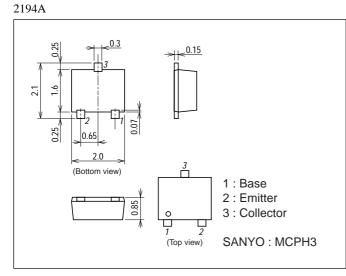
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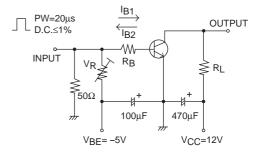
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Collector-to-Emitter Saturation Voltage	VCE(sat)	IC=750mA, IB=15mA		115	175	mV
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	IC=750mA, IB=15mA		0.83	1.2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC=10μA, IE=0	40			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=1mA, RBE=∞	30			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =10μA, I _C =0	5			V
Turn-ON Time	ton	See specified Test Circuit.		35		ns
Storage Time	tstg	See specified Test Circuit.		205		ns
Fall Time	tf	See specified Test Circuit.		32		ns

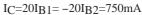
Package Dimensions

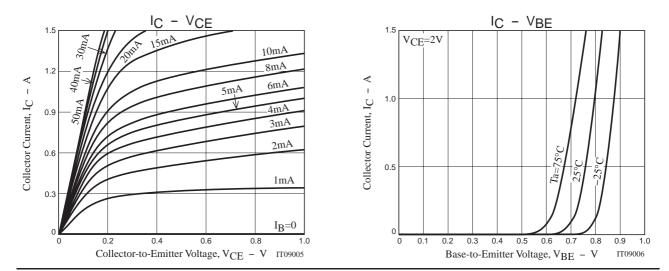
unit : mm

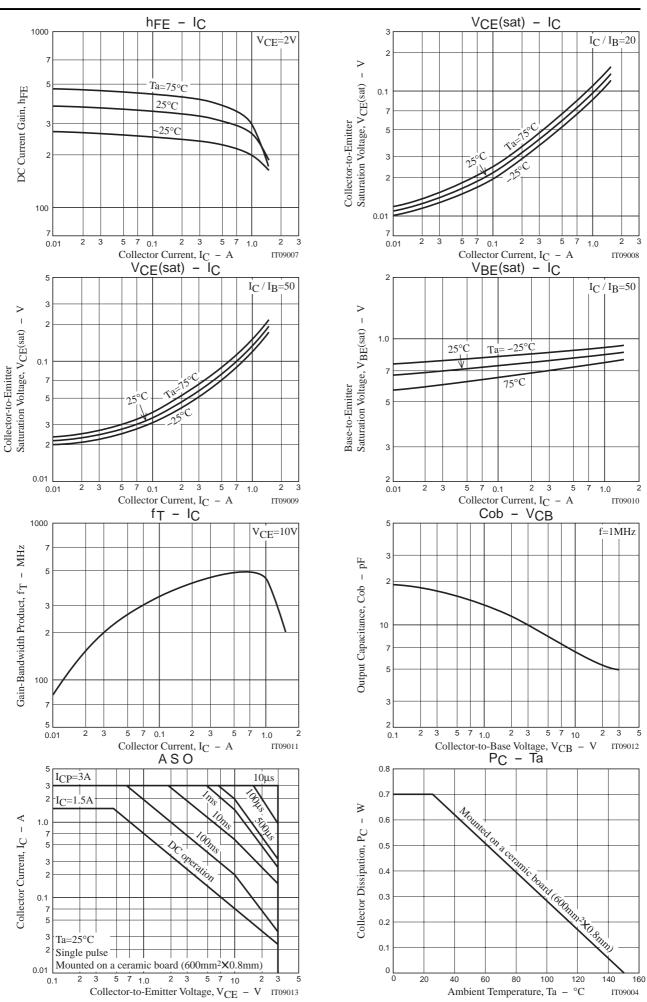


Switching Time Test Circuit









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